

## Assignment 1 (EE620) (23-01-2019)

Values for reference:

$T_{ox} = 5 \text{ nm}$

$N_A = 10^{17} / \text{cm}^3$

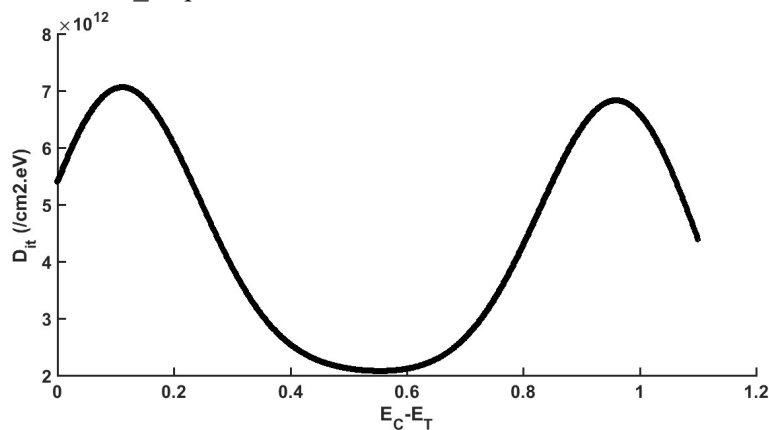
Fermi level of gate is at the conduction band of n+ type Si.

(Note: If any data is missing then assume an appropriate value and clearly mention your assumption)

1. Obtain a plot for total substrate charge,  $|Q|$  versus potential at oxide/semiconductor interface (band bending  $\psi_s$ ), for an MOS capacitor. [5 M]

$$Q = -\epsilon_{si} \left( -\frac{d\psi_s}{dx} \right) = \pm \sqrt{2\epsilon_{si} kT N_A} \left[ (e^{-q\psi_s/kT} + \frac{q\psi_s}{kT} - 1) + \frac{n_i^2}{N_A^2} (e^{q\psi_s/kT} - \frac{q\psi_s}{kT} - 1) \right]^{1/2}$$

2. Obtain a plot for potential at oxide/semiconductor interface (i.e. band bending  $\psi_s$ ) versus gate bias ( $V_G$ ) for an MOS capacitor. slide33 [5 M]
3. Obtain LFCV (low frequency C-V) and HFCV (High frequency C-V) curves using the equation for Q. Do the derivative manually and then compare with the numerical derivation. [10 M]
4. Vary oxide thickness ( $T_{ox}=3, 5, 7\text{nm}$  for  $N_A=1e17$ ) and doping ( $N_A=1e14, 1e16$  &  $1e18 / \text{cc}$  for  $T_{ox}=5\text{nm}$ ) and see the variations in C-V. Try to explain your observations. [10 M]
5. Do the above calculations (Q1 to Q4) using depletion approximation and show the comparative plots. [10 M]
6. Assume a fixed uniform oxide charge density  $\rho(x)=1e18/\text{cc}$  throughout the oxide. Show the shift in the C-V curves. [5 M]
7. An interface trap profile is shown in the figure below. Using a similar  $D_{it}$  profile and assuming the charge neutrality point to be located at mid gap, calculate  $G_p$  and  $C_p$  for the frequencies (1e3, 1e4, 1e5, 1e6) Hz. To calculate  $\tau$  use  $n_i=1.5e10$ ,  $v_{th}=2.6e7$ ,  $\sigma=1e-15$ . From this, calculate  $C_M$  and  $G_M$ . Plot  $V_g$  vs  $C_M(\omega)$  (Both LFCV and HFCV). (Note : You should obtain a stretch in C-V). (Meaning of the terms and required equations can be found in the lecture slide 'Set\_04.pdf').



Equation for  $D_{it}$  is given blow

$$\sum_{i=1}^3 A_i \exp\left(-\left(\frac{E_{it} - B_i}{C_i}\right)^2\right)$$

where;  $A_1=A_2=6e12, A_3=2e12$ ;  $B_1=0.1, B_2=0.97, B_3=0.5$ ;  $C_1=C_2=0.2, C_3=0.5$ . ( You can have your own similar ‘U’ shaped  $D_{it}$  ). [15 M]